

Refine Search

Search Results -

Terms	Documents
L4 and nitride	95

Database:
US Pre-Grant Publication Full-Text Database
US Patents Full-Text Database
US OCR Full-Text Database
EPO Abstracts Database
JPO Abstracts Database
Derwent World Patents Index
IBM Technical Disclosure Bulletins

Search:

L5

Refine Search

Recall Text Clear Interrupt

Search History

DATE: Friday, March 18, 2005 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u>	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u>
side by side			result set
DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=OR			
<u>L5</u>	L4 and nitride	95	<u>L5</u>
<u>L4</u>	capacitor and ((ALD or (atomic adj layer adj deposition)) with (aluminum adj oxide))	120	<u>L4</u>
<u>L3</u>	L2 and (ALD or (atomic adj layer adj deposition))	20	<u>L3</u>
<u>L2</u>	L1 and (aluminum adj oxide)	47	<u>L2</u>
<u>L1</u>	MIS adj capacitor	824	<u>L1</u>

END OF SEARCH HISTORY